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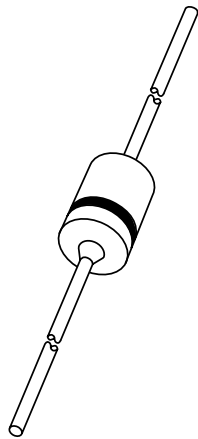
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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DATA SHEET



BAV20; BAV21 General purpose diodes

Product data sheet
Supersedes data of 1996 Sep 17

1999 May 25

General purpose diodes

BAV20; BAV21

FEATURES

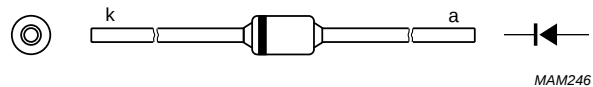
- Hermetically sealed leaded glass SOD27 (DO-35) package
- Switching speed: max. 50 ns
- General application
- Continuous reverse voltage: max. 150 V, 200 V
- Repetitive peak reverse voltage: max. 200 V, 250 V
- Repetitive peak forward current: max. 625 mA.

APPLICATIONS

- General purposes in industrial equipment e.g. oscilloscopes, digital voltmeters and video output stages in colour television.

DESCRIPTION

The BAV20 and BAV21 are switching diodes fabricated in planar technology, and encapsulated in hermetically sealed leaded glass SOD27 (DO-35) packages.



The diodes are type branded.

Fig.1 Simplified outline (SOD27; DO-35) and symbol.

General purpose diodes

BAV20; BAV21

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage				
	BAV20		–	200	V
	BAV21		–	250	V
V_R	continuous peak reverse voltage				
	BAV20		–	150	V
	BAV21		–	200	V
I_F	continuous forward current	see Fig.2; note 1	–	250	mA
I_{FRM}	repetitive peak forward current		–	625	mA
I_{FSM}	non-repetitive peak forward current	square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4			
		$t = 1\text{ }\mu\text{s}$	–	9	A
		$t = 100\text{ }\mu\text{s}$	–	3	A
		$t = 1\text{ s}$	–	1	A
P_{tot}	total power dissipation	$T_{amb} = 25\text{ °C}$; note 1	–	400	mW
T_{stg}	storage temperature		–65	+175	°C
T_j	junction temperature		–	175	°C

Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

General purpose diodes

BAV20; BAV21

ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_F	forward voltage	see Fig.3 $I_F = 100\text{ mA}$ $I_F = 200\text{ mA}$	– –	1.0 1.25	V V
I_R	reverse current	see Fig.5 $V_R = V_{Rmax}$ $V_R = V_{Rmax}$; $T_j = 150\text{ }^{\circ}\text{C}$	– –	100 100	nA μA
C_d	diode capacitance	$f = 1\text{ MHz}$; $V_R = 0$; see Fig.6	–	5	pF
t_{rr}	reverse recovery time	when switched from $I_F = 30\text{ mA}$ to $I_R = 30\text{ mA}$; $R_L = 100\text{ }\Omega$; measured at $I_R = 3\text{ mA}$; see Fig.8	–	50	ns

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length 10 mm; note 1	375	K/W

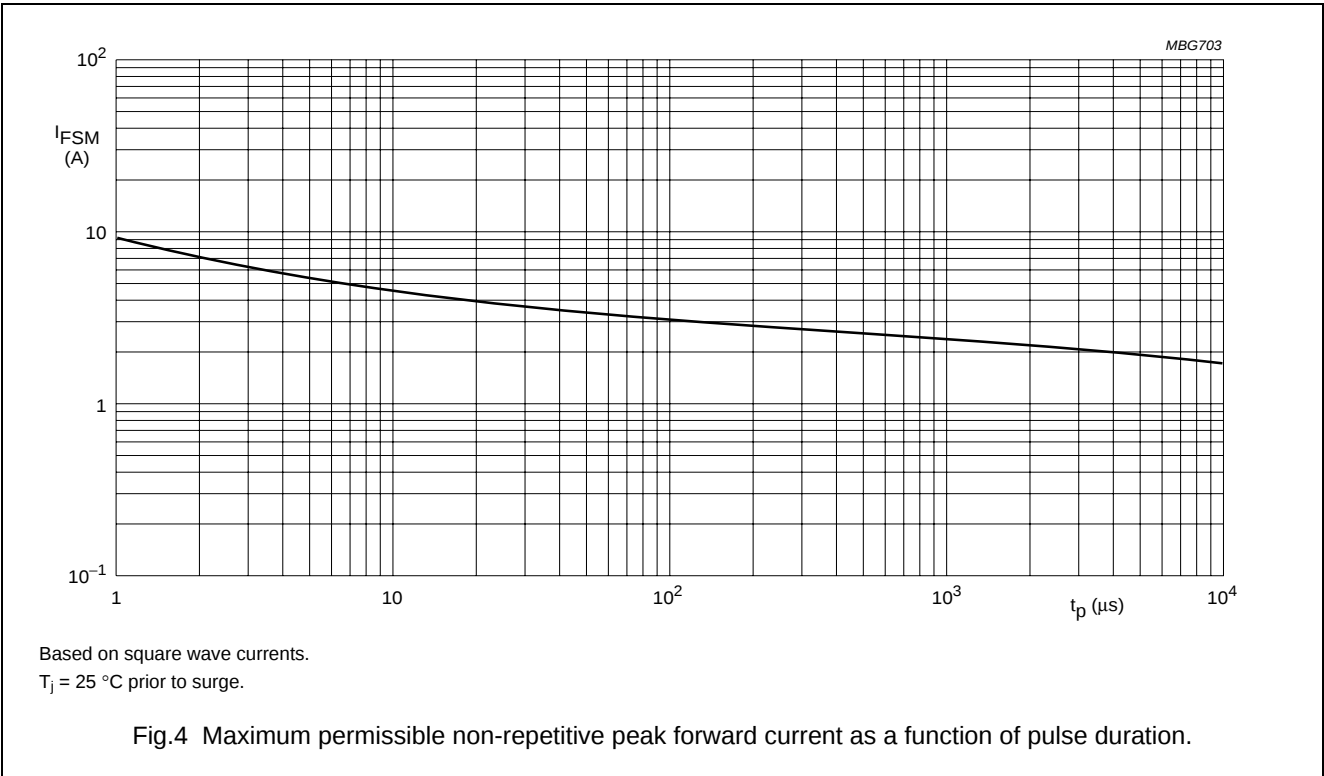
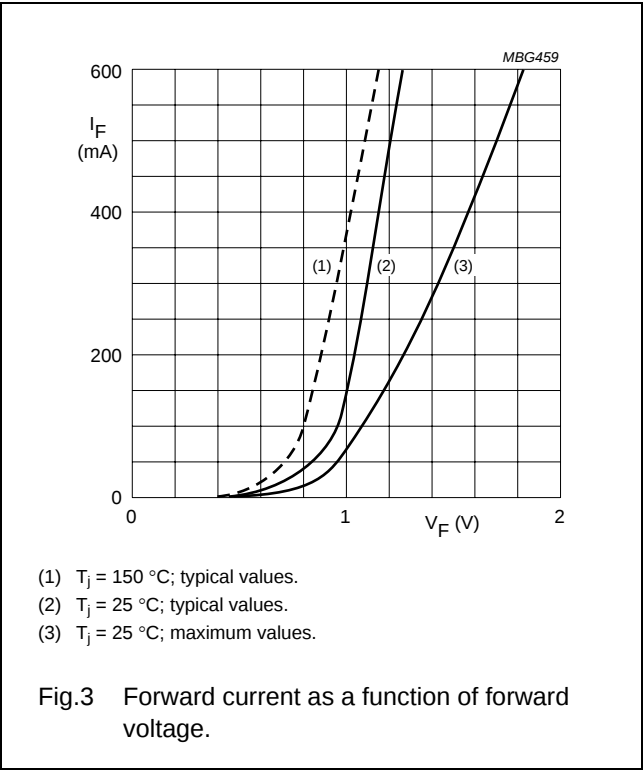
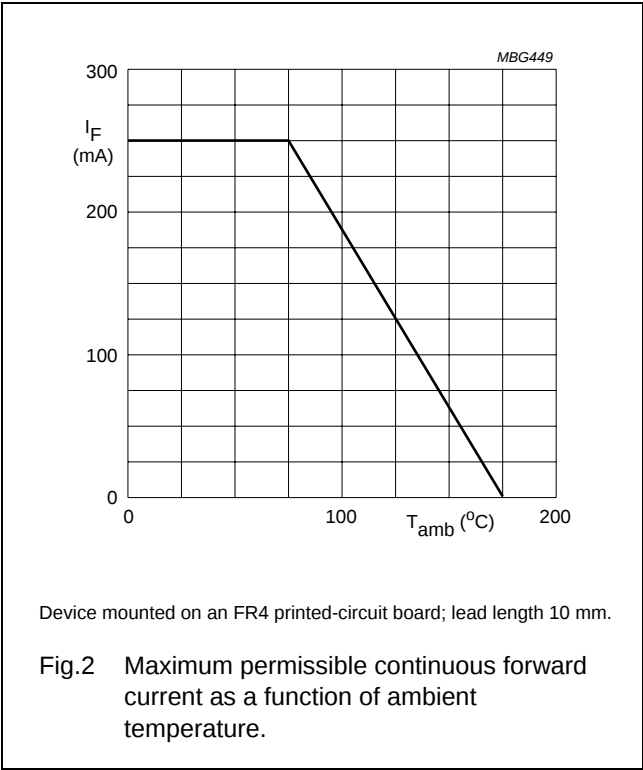
Note

1. Device mounted on a printed circuit-board without metallization pad.

General purpose diodes

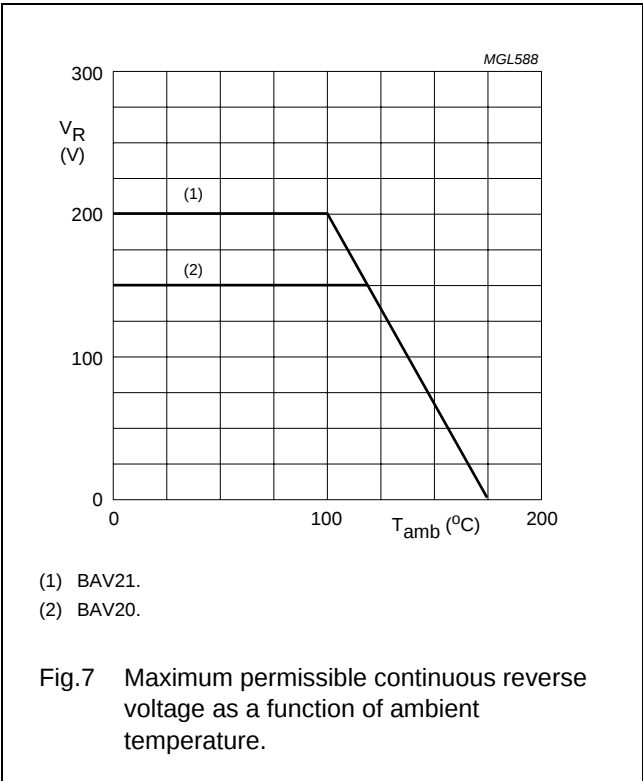
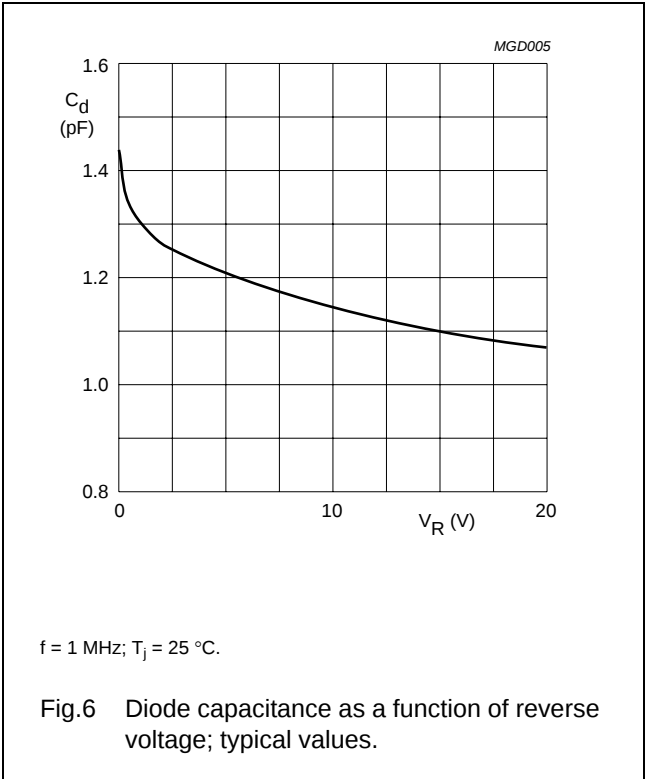
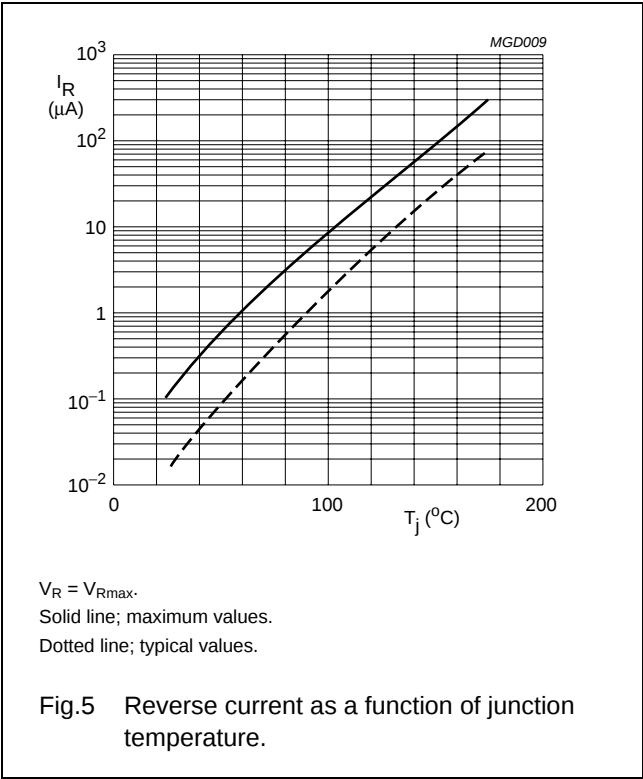
BAV20; BAV21

GRAPHICAL DATA



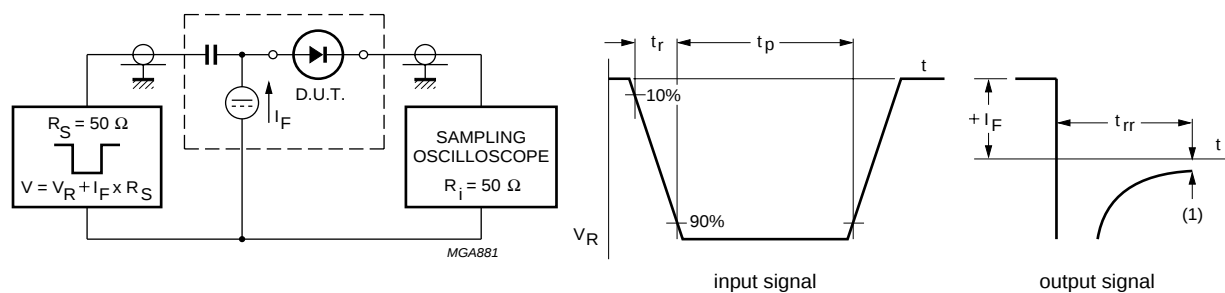
General purpose diodes

BAV20; BAV21



General purpose diodes

BAV20; BAV21



(1) $I_R = 3\text{ mA}$.

Fig.8 Reverse recovery voltage test circuit and waveforms.

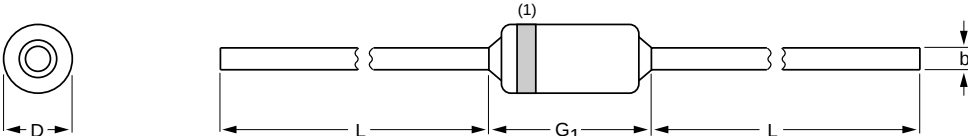
General purpose diodes

BAV20; BAV21

PACKAGE OUTLINE

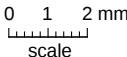
Hermetically sealed glass package; axial leaded; 2 leads

SOD27



DIMENSIONS (mm are the original dimensions)

UNIT	b max.	D max.	G ₁ max.	L min.
mm	0.56	1.85	4.25	25.4



Note

1. The marking band indicates the cathode.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOD27	A24	DO-35	SC-40			97-06-09

General purpose diodes

BAV20; BAV21

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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NXP Semiconductors

Customer notification

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Contact information

For additional information please visit: **<http://www.nxp.com>**

For sales offices addresses send e-mail to: **salesaddresses@nxp.com**

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